



# **DATA SHEET**

# **MMBT3904**

## NPN GENERAL PURPOSE SWITCHING TRANSISTOR

**FEATURES** 

VOLTAGE 40 Volts POWER

225 mWatts

- NPN epitaxial silicon, planar design
- Collector-emitter voltage VCE = 40V
- Collector current IC = 200mA
- Pb free product are available: 99% Sn above can meet Rohs environment substance directive request

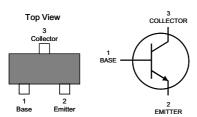
#### **MECHANICAL DATA**

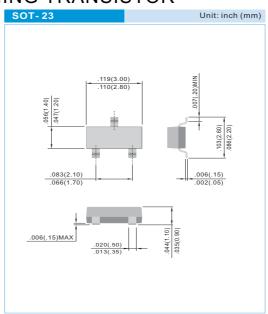
Case: SOT-23, Plastic

Terminals: Solderable per MIL-STD-202G, Method 208

Approx. Weight: 0.008 gram

Marking: S1A





#### **ABSOLUTE RATINGS**

PARAMETER	Sym bol	Value	Units	
Collector-EmitterVolage	Vceo	40	V	
Collector-Base Volage	VcBo	60	V	
Em itter-Base Volage	VEBO	6.0	V	
CollectorCument-Continuous	Ic	200	m A	

#### THERMAL CHARACTERISTICS

PARAMETER	Sym bol	Value	Units	
Max PowerDissipation (Note 1)	Ртот	225	m W	
Therm alResistance, Junction to Am bient	R <b>0</b> ja	556	°C /M	
Junction Tem perature	Тл	-55 to 150	°C	
Storage Tem perature	TETG	-55 to 150	°C	

Note 1: Transistor mounted on FR-5 board 1.0 x 0.75 x 0.062 in.

STAD-NOV.26.2004 PAGE . 1



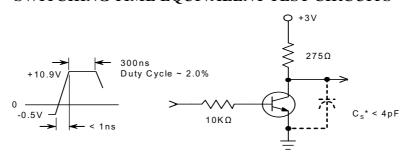


#### **ELECTRICAL CHARACTERISTICS TA=25°C**

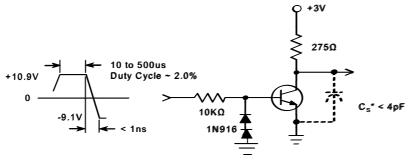
PARAMETER	Symbol	Test Condition	MIN.	TYP.	MAX.	Units
Collector - Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	IC=1.0mA, IB=0	40	-	-	V
Collector - Base Breakdown Voltage	V <sub>(BR)</sub> CBO	IC=10uA, IE=0	60	-	-	V
Emitter - Base Breakdown Voltage	V <sub>(BR)</sub> EBO	IE=10uA, IC=0	6.0	-	-	V
Base Cutoff Current	İBL	VCE=30V, VEB=3.0V	-	-	50	nA
Collector Cutoff Current	Icex	VCE=30V, VEB=3.0V	-	-	50	nA
DC Current Gain (Note 2)	h <sub>FE</sub>	IC=0.1mA, VCE=1.0V IC=1.0mA, VCE=1.0V IC=10mA, VCE=1.0V IC=50mA, VCE=1.0V IC=100mA, VCE=1.0V	40 70 100 60 30	- - - -	- - 300 - -	-
Collector - Emitter Saturation Voltage (Note 2)	VCE(SAT)	IC=10mA, IB=1.0mA IC=50mA, IB=5.0mA	-	-	0.2 0.3	V
Base - Emitter Saturation Voltage (Note 2)	VBE(SAT)	IC=10mA, IB=1.0mA IC=50mA, IB=5.0mA	0.65	-	0.85 0.95	V
Collector - Base Capacitance	Ссво	VCB=5V, IE=0, f=1MHz	-	-	4.0	pF
Emitter - Base Capacitance	Сево	VCB=0.5V, IC=0, f=1MHz	-	-	8.0	pF
Delay Time	td	VCC=3V,VBE=-0.5V, IC=10mA,IB=1.0mA	-	-	35	ns
Rise Time	tr	VCC=3V,VBE=-0.5V, IC=10mA,IB=1.0mA	-	-	35	ns
Storage Time	ts	Vcc=3V,Ic=10mA IB1=IB2=1.0mA	-	-	200	ns
Fall Time	tf	VCC=3V,IC=10mA IB1=IB2=1.0mA	-	-	50	ns

Note 2: Pulse Test: Pulse Width < 300 us, Duty Cycle < 2.0%.

# SWITCHING TIME EQUIVALENT TEST CIRCUITS



Delay and Rise Time Equivalent Test Circuit



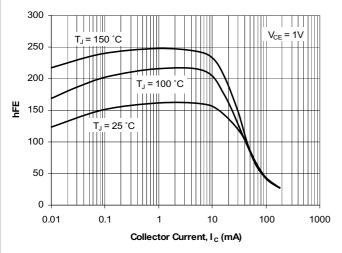
Storage and Fall Time Equivalent Test Circuit

STAD-NOV.26.2004 PAGE . 2









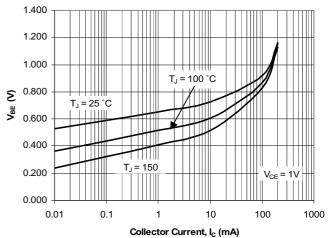
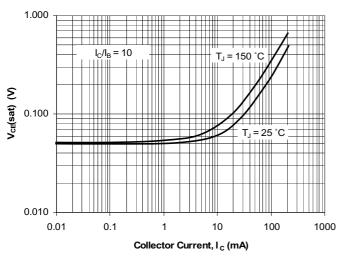


Fig. 1. Typical h<sub>FE</sub> vs Collector Current

Fig. 2. Typical  $V_{\text{BE}}$  vs Collector Current



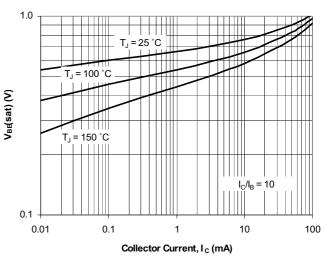


Fig. 3. Typical V<sub>CE</sub> (sat) vs Collector Current

Fig. 4. Typical V<sub>BE</sub> (sat) vs Collector Current

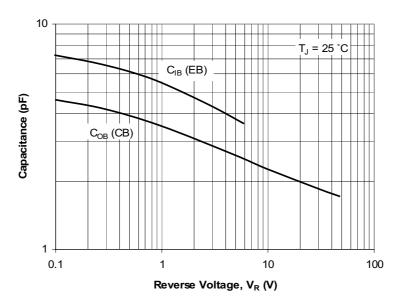


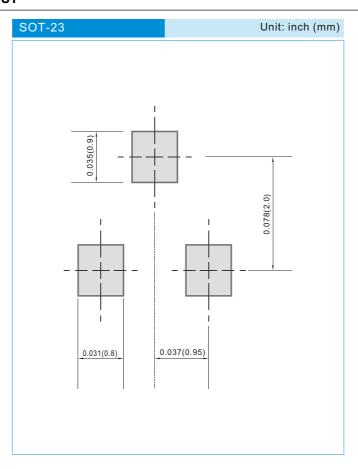
Fig. 5. Typical Capacitances vs Reverse Voltage

STAD-NOV.26.2004 PAGE . 3





#### MOUNTING PAD LAYOUT



#### **ORDER INFORMATION**

· Packing information

T/R - 12K per 13" plastic Reel

T/R - 3.0K per 7" plastic Reel

#### **LEGAL STATEMENT**

### IMPORTANT NOTICE

This information is intended to unambiguously characterize the product in order to facilitate the customer's evaluation of the device in the application. The information will help the customer's technical experts determine that the device is compatible and interchangeable with similar devices made by other vendors. The information in this data sheet is believed to be reliable and accurate. The specifications and information herein are subject to change without notice. New products and improvements in products and product characterization are constantly in process. Therefore, the factory should be consulted for the most recent information and for any special characteristics not described or specified.

#### Copyright Pan Jit International Inc. 2003

All rights reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract. The information presented is believed to be accurate and reliable, and may change without notice in advance. No liability will be accepted by the publisher for any consequence of use. Publication thereof does not convey nor imply any license under patent or other industrial or intellectual property rights.

STAD-NOV.26.2004 PAGE . 4